

VT-RT6M

Bluetooth® Low Energy Module

Version 1.2 Release

INTRODUCTION

VT-RT6M is an ultra-low-power SoC module for Bluetooth® 5.3 low energy applications that combines the excellent performance of a leading RF transceiver with a low-power ARM[®] Cortex-M4F and rich powerful supporting features and peripherals. The VT-RT6M supports Bluetooth® mesh networking specification suited for largescale device networks to support building automation, sensor networks, asset tracking and other solutions where multiple devices need to communicate reliably and securely.

FEATURES

- Bluetooth® Core Spec v5.3 compliant
- Supports Bluetooth Mesh Networking Specification
- Supports AES128/192/256 encryption/decryption
- Supports OTA (Over-the-Air) for firmware upgrade
- AT-Command supported for easy project development

	Battery Supply Voltage	1.8V to 3.6V
•	Operational Temperature	-30°C to +85°C

Current Consumptions

Power Down Mode	450nA (Typ.)
Deep LPS (with 160K SRAM retention) Mode	2.5uA (Typ.)
TX Mode (+0dBm)	8.4mA (Typ.)
TX Mode (+4dBm)	10.4mA (Typ.)
TX Mode (+8dBm)	12.7mA (Typ.)
RX Mode	6.8mA (Tvp.)

- Radio Bluetooth® Qualification, **DID: D066920** (Bluetooth SIG listing declaration ID attached in the last section)
- Meets Radio Certification FCC, RED, MIC Japan and NCC TW
- Dimension 11.05mm(W) x 17.0mm(L) x 2.1mm(H)
- Pb Free, RoHS Compliant



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REVERSION HISTORY

Version Code	Date	Descriptions
0.52 BETA	7-MAY-19	Preliminary release
0.52.0574	6 IIIN 10	Change module part no.;
0.53 BETA	6-JUN-19	Update operational temperature range;
		Add module block diagram;
	4-SEP-19	Add AT Command mode pin definitions;
0.60 BETA		Add module interface descriptions;
		Add module electrical characteristics;
		Add PCB layout guide;
1.0	21-Dec-20	Add RF certifications
1.1	8-Apr-22	Update module information
1.2	22-Jan-24	Upgrade Bluetooth version and SIG listing declaration ID

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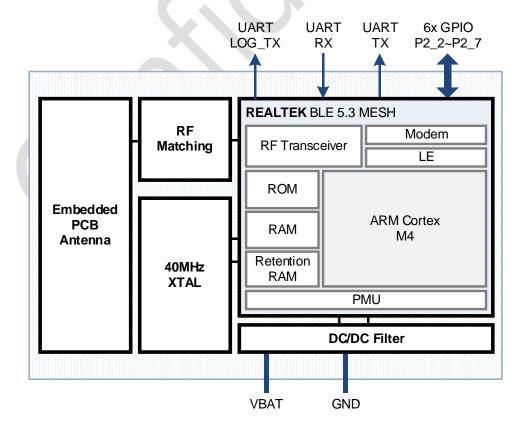
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MODULE SPECIFICATIONS

Specificat	ion Name	Descriptions
Module Dimension		11.05mm(W) x 17mm(L) x 2.1mm(H)
BLE Core Compliant		BLE V5.3
Operation Distance		Up to 80Meters (*LE 1M, apple to apple testing results)
Power Supply		1.8V – 3.6V
	Power Down Mode	450nA
	Deep LPS	2.5uA
	TX mode (+0dBm)	8.4mA
Power Consumption	TX mode (+4dBm)	10.4mA
	TX mode (+8dBm)	12.7mA
	RX mode	6.8mA
Antenna Type		embedded PCB antenna
GPIO Numbers:		Up to 8x (including P3_0 and P3_1)
PWM Numbers:		Up to 6x (P2_2 to P2_7)
12bit ADC Numbers:		Up to 6x (P2_2 to P2_7)
Support interfaces		UART/4-wire SPI master/4-wire SPI slave

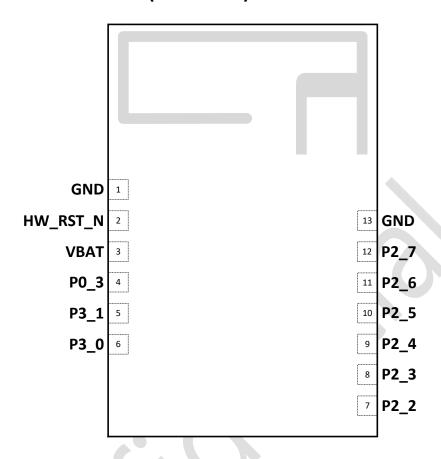
■ BLOCK DIAGRAM •



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PIN ASSIGNMENTS (TOP VIEW)



PIN DEFINITIONS

SoC Mode Condition:

Note: INOUT (digital bidirectional), ANA(analog pin), DIG(digital pin).

#	Pin Name	I/O	Ana/Dig	Function
1	GND	,	GND	GND
2	HW_RST_N	IZ	DIG	Hardware reset pin; low active;
3	VBAT	1	PWR	Power Supply, 1.8V to 3.6V;
4	P0_3	OUT	DIG	LOG_UART_TX (default)
5	P3_1	INOUT	DIG	HCI_UART_RX (default) General purpose IO, 8mA driving capability; With wakeup function, internal strong/weak pull-up and pull-down;
6	P3_0	INOUT	DIG	HCI_UART_TX (default) General purpose IO, 8mA driving capability; With wakeup function, internal strong/weak pull-up and pull-down;



	P2_2			AUXADC input 2 (default) General purpose IO, 8mA driving capability;
7		INOUT	ANA/DIG	
				With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 3 (default)
8	P2 3	INOUT	ANA/DIG	General purpose IO, 8mA driving capability;
	12_3	111001	71107 9 210	With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 4 (default)
			ANA/DIG	General purpose IO, 8mA driving capability;
9	P2_4	INOUT		With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 5 (default)
10			ANIA/DIC	General purpose IO, 8mA driving capability;
10	P2_5	INOUT	ANA/DIG	With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 6 (default)
				General purpose IO, 8mA driving capability;
11	P2_6	INOUT	ANA/DIG	With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 7 (default)
12		INOUT	ANIA/DIC	General purpose IO, 8mA driving capability;
12	P2_7			With wakeup function, internal strong/weak pull-up and pull-
				down;
13	GND	-	GND	GND

UART AT Command Mode Condition:

Note: ANA(analog pin), DIG(digital pin).

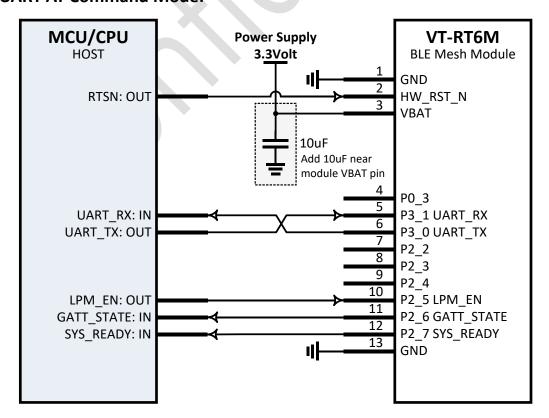
#	Pin Name	I/O	Ana/Dig	Function
1	GND	ı	GND	GND
2	HW_RST_N	IN	DIG	Hardware reset pin; low active;
3	VBAT	-	PWR	Power Supply, 1.8V to 3.6V;
4	PO_3	OUT	DIG	LOG_UART_TX (default) for debugging purposed; Keep floating for general usage;
5	P3_1	IN	DIG	UART_RX; With weakly pull-high;
6	P3_0	OUT	DIG	UART_TX;



7	P2_2	IN	ANA	NC, keep floating for general usage; With weakly pull-low;
8	n2 2	IN	ANA	NC, keep floating for general usage;
ð	P2_3	IIN	ANA	With weakly pull-low;
9	P2_4	IN	ANA	NC, keep floating for general usage;
,	12_4	110	ANA	With weakly pull-low;
				LPM_EN;
10	P2_5	IN	DIG	Enable low power mode, high active;
				With weakly pull-low;
				GATT_STATE;
11	D2 C	OUT	DIC	Indication pin for GATT connection state;
11	P2_6	OUT	DIG	Output high when connected;
				Output low when disconnected;
				SYS_READY;
12	D2 7	OUT	DIC	indication pin for BLE stack ready;
12	P2_7	P2_7 OUT	DIG	Output high when BLE stack ready;
				Output low when BLE stack not ready;
13	GND	-	GND	GND

■ APPLICATION EXAMPLE

UART AT Command Mode:



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INTERFACE DESCRIPTIONS

UART

VT-RT6M provides multiple UART baud-rate. The common baud-rate is shown in below table. The UART clock error between two devices should be less than +/- 2.5%.

VT-RT6M UART Features:

- Supports 7/8 data format.
- 1/2 bit stop bit.
- Configurable parity bit: odd/even.
- Programmable baud rate (maximum baud rate=4Mbps).
- Support hardware flow control.
- RX line idle state detect.
- DMA supported.

Baud-rate (bps)	Error (%)	Baud-rate (bps)	Error (%)
1200	-0.23	460800	0.17
9600	< 0.01	500000	< 0.01
14400	< 0.01	921600	0.18
19200	< 0.01	1000000	< 0.01
28800	< 0.01	1382400	0.17
38400	< 0.01	1444400	-0.31
57600	< 0.01	1500000	< 0.01
76800	0.01	1843200	-0.35
115200	< 0.01	2000000	0.02
128000	0.02	2764800	0.14
153600	-0.1	3000000	0.06
230400	0.03	400000	0.03

Table: UART Baud Rate



ELECTRICAL CHARACTERISTICS

Temperature Limit Ratings

Parameter	Description	Note	Min.	Тур.	Max.	Unit
T _{STORE}	Storage temperature		-55		125	°C
T _{AOP}	Operational Temperature		-30		85	°C

Power Supply DC Characteristics

Parameter	Description	Note	Min.	Тур.	Max.	Unit
V_{BAT}	Supply Voltage		1.8	3	3.6	V

ESD Characteristics

Parameter	Description	Note	Min.	Тур.	Max.	Unit
ESD _{нвм}	ESD, human body mode	All pins, test method: JESD22			3500	V
ESD _{MM}	ESD, machine mode	All pins, test method: JESD22			200	V
ESD _{CDM}	ESD, charged device mode	All pins, test method: JESD22			500	V

12bit-AUX ADC Characteristics

Parameter	Description	Note	Min.	Тур.	Max.	Unit
ADCBIT	Resolution	Bypass mode		12		BITS
ADCBIT	Resolution	Divided mode (1/3.3)		12		BITS
F _{CLK_ADC}	Clock Source	From digital			400	kHz
		Single-ended mode		±1.5		LSB
ADC.	ADC _{DNL} DNL	(Bypass mode)		±1.5		LSB
ADCONL		Differential mode		±3.0		LSB
		(Bypass mode)		±3.0		LSB
		Single-ended mode		±1.0		LSB
ADCINI	INL	(Bypass mode)		11.0		LSB
ADCINE	IINL	Differential mode		±2.0		LSB
		(Bypass mode)		12.0		LSB
		External channel	0		VBAT	V
		(Divided Mode)	U		VDAT	V
۸DC	Input Voltage Range	External channel	0		1	
ADC _{VIN_RANGE}	input voitage hange	(Bypass Mode)	U		1	
		Internal channel	1.8	,	2.62	V
		(VBAT)	1.0		3.63	V



ADC	Innut Impodono	Bypass mode	10M	Ohm
ADC_R_IN	Input Impedance	Resistor divider mode (1/4)	500k	Ohm
ADC	Bypass mode	1.9	pF	
ADC_{C_Sample}	Input Impedance	Resistor divider mode (1/4)	1.9	pF

Radio Characteristics

General Radio Characteristics

Parameter	Description	Note	Min.	Тур.	Max.	Unit
F _{RANGE}	Frequency range		2402		2480	MHz

RX Performance

Condition: VBAT=3V, ambient temperature=25°C

Parameter	Description	Note	Min.	Тур.	Max.	Unit
P _{RX_MIN}	Sensitivity (LE 1M)	PER ≤ 30.8%	-97			dBm
P _{RX_MAX}	Maximum received power	PER ≤ 30.8%		-1		dBm
	C/I co-channel		21			dB
	C/I + 1MHz offset		15			dB
	C/I - 1MHz offset		15			dB
	C/I + 2MHz offset		-17			dB
CI _{RX_1M}	C/I - 2MHz offset		-15			dB
	C/I + 3MHz offset		-27			dB
	C/I image C/I image + 1MHz offset		-9			dB
)	-15			dB
	C/I image - 1MHz offset		-15			dB
		30MHz ~ 2000MHz	-30			dBm
	Blocker Power	2003MHz ~ 2399MHz	-30			dBm
Р _{RX_ООВ}	Wanted signal level= -	2484MHz ~ 2997MHz	-30			dBm
	67dBm	3000MHz ~ 12.75GHz	-30			dBm
PER _{MAX}	Max PER report integrity	Wanted signal= -30dBm		50%		-
		Wanted signal f(0) = -64dBm				
	Name to be a more advisable to the control	Worst intermodulation level				-ID
P _{RX_IMD}	Max Intermodulation level	@2f1-f2=f0, f1-f2 =n MHz,	-50			dBm
		n=3,4,5				



TX Performance

Condition: VBAT=3V, ambient temperature=25°C

Parameter	Description	Note	Min.	Тур.	Max.	Unit
P _{TX_MAX}	Maximum output power				8	dBm
	A dia contrabanno di manuori	+2MHz			-20	dBm
D	Adjacent channel power ratio	-2MHz			-20	dBm
P_{TX_ADJ}		≥ +3MHz			-30	dBm
	(LE 1M)	≤ -3MHz			-30	dBm
		Δf1avg		250		kHz
r	Modulation Characteristics	Δf2max	185			kHz
F _{MOD}	(LE 1M)	Δf2max pass rate		100%		-
		Δf2avg / Δf1avg		0.88		-
	Comica fue account offset and	Average Fn		12.5		kHz
r	Carrier frequency offset and drift	Drift rate		10		kHz/50μs
F _{CAR_OFFSET}	(LE 1M)	Average drift		10		kHz/50μs
	(LE IIVI)	Maximum drift		10		kHz/50μs
P _{TX_HD2}	2 nd harmonic power			-50		dBm
P _{TX_HD3}	3 rd harmonic power			-50		dBm

Digital I/O Pin DC Characteristics

Condition: ambient temperature=25°C

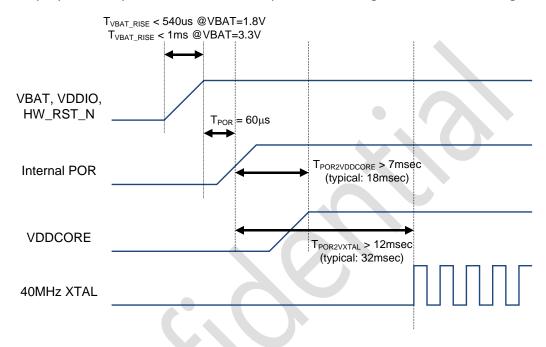
Parameter	Description	Note	Min.	Тур.	Max.	Unit
V _{IH33}	Input high voltage	•	2	3.3	3.6	V
V _{IL33}	Input low voltage	VDDIO 3.3V		0	0.9	V
V _{OH33}	Output high voltage	VDDIO=3.3V	2.97		3.3	V
V _{OL33}	Output low voltage		0		0.33	V
V _{1H28}	Input high voltage		1.8	2.8	3.1	V
V _{IL28}	Input low voltage	VDDIO-3.8V		0	0.8	V
V _{OH28}	Output high voltage	VDDIO=2.8V	2.5			V
V _{OL28}	Output low voltage		0		0.28	V
	Strong Dull	VDDIO=3.3V		10		kOhm
	Strong Pull	VDDIO=1.8V		20		kOhm
D	Wook Pull	VDDIO=3.3V		100		kOhm
R _{pull}	Weak Pull	VDDIO=1.8V		200		kOhm
	Strong Pull	VDDIO=3.3V		5		kOhm
	(P2_2~P2_7)	VDDIO=1.8V		2.5		kOhm



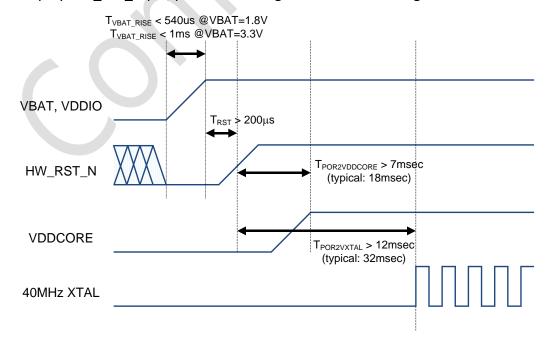
D ::	Weak Pull	VDDIO=3.3V	50		kOhm
R_{pull}	(P2_2~P2_7)	VDDIO=1.8V	25		kOhm
Іін	Input high current	PAD configured as input		0.1	μΑ
lıL	Input low current	mode		0.1	μΑ

Boot Sequence

Boot up by internal power on reset circuit, power on timing is shown in below figure.

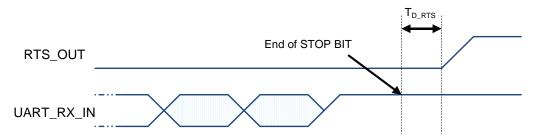


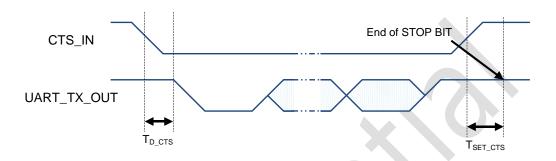
Boot up by HW_RST_N pin, power on timing is shown in below figure.





UART Characteristics

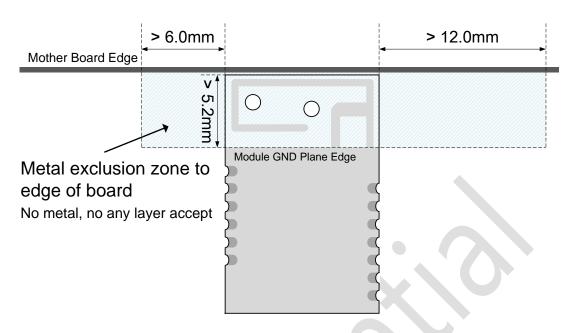




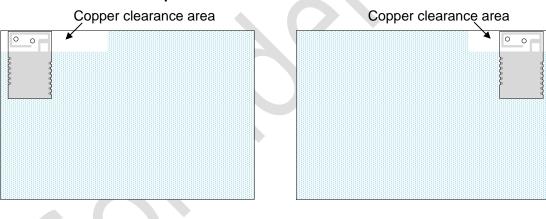
Parameter	Description	Note	Min.	Тур.	Max.	Unit
Timing between UART_RX_IN stop bit and					0.5	nc
T_{D_RTS}	RTS rising edge when RX FIFO is full				0.5	ns
т	Timing between CTS falling edge and				25	200
T _{D_CTS}	UART_TX_OUT first bit				25	ns
T	Timing between CTS rising edge and		75			nc
T _{SET_CTS}	UART_TX_OUT stop bit		/5			ns

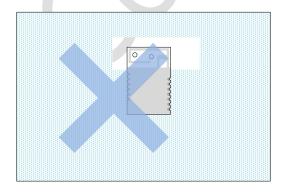


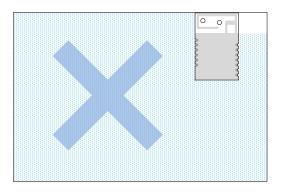
PCB LAYOUT GUIDE



Module Placement Example:

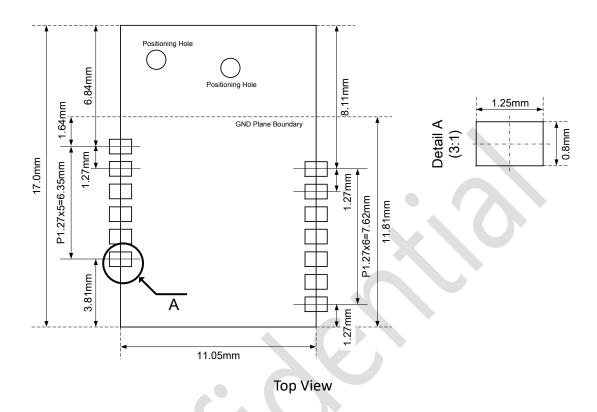


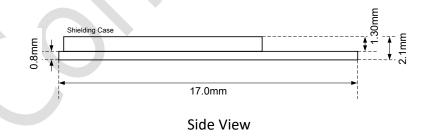






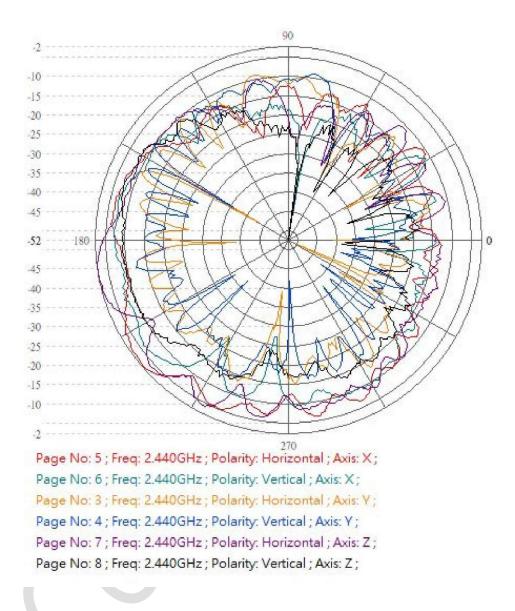
MODULE DIMENTIONS







ANTENNA TEST REPORT





■ BQB LISTING



Project Details	

Project Name VT-RT6M Referenced Qualified Design(s) 194774 Listing Date 2024-01-09 Declaration ID D066920 Product Listing(s) Name Website Category Publish Date Model Number Description VT-RT6M Unique Products 1/9/2024 12:00:00 AM VT-RT6M Bluetooth 5.3 Low Energy Modules
Listing Date 2024-01-09 Declaration ID D066920 Product Listing(s) Name Website Category Publish Date Model Number Description
Declaration ID D066920 Product Listing(s) Name Website Category Publish Date Model Number Description
Product Listing(s) Name Website Category Publish Date Model Number Description
Name Website Category Publish Date Model Number Description
VT-RT6M Unique Products 1/9/2024 12:00:00 AM VT-RT6M Bluetooth 5.3 Low Energy Module
VT-RT6MB Unique Products 1/9/2024 12:00:00 AM VT-RT6MB Blueboth 5.3 Low Energy Module
Member Company Mediawave
Declaring Member Contact / Listing Contact Person Name Tainder Yeh
Address 1F.,No.314,Jhongsiao 1st rd., Toufen Township,Maoli County 351,Taiwan
City
State
Country Taiwan
Postal Code

Complete the Project and Submit Product(s) for Qualification

By typing my name or other symbol of my signature into the "Signature" field below, I agree on behalf of Mediawave ("Company") to Bluetooth Launch Studio Terms of Use, and I make the following representations and warranties personally and on behalf of Company. The following representations and warranties, together with all project information and the Bluetooth Launch Studio Terms of Use, are the Supplier Declaration of Conformity and Declaration of Compliance described in the Program Reference Document (PRD) and Declaration Process Document

- I am authorized by Company to submit all of the information included in this project and all information is complete and accurate.
- one signatory, a stamp or seal, or a witnessed signature to be legally bound.
- I agree on behalf of Company to contract in English and electronically, and adopt the characters and symbols input in the signature field below as my signature, with the same effect as an ink signature.
- The products included in this project are owned and distributed by Company under a Product name that identifies Company as the source of the Product. Company has the right to use and reference all Qualified Designs referenced in the project, and the products and referenced Qualified Designs comply with the version of the Bluetooth Specification identified in the project submission.
- ▼ The product(s) included in this project and the corresponding Qualified Designs comply with the Bluetooth Launch Studio Terms of Use.



BLUETOOTH RF TEST





Bluetooth® Qualification Test Facility (BQTF) recognized by the Bluetooth SIG.

Test Report No: 23C0680R-A336410010-A

Bluetooth RF Test Report

Identification of item:	VT-RT6M · VT-RT6MB
Trademark:	MediaWave
Model or type reference:	VT-RT6M · VT-RT6MB
Serial number:	NA
Final HW version:	V1
Final SW version:	V1
Manufacturer:	Liansong Metal Products Factory A Building, Mapu'ao Industrial Area, Sanlian Village, Fenggang Town, Dongguan City, Guangdon Province, China.
Test method requested:	The testing on demand according to RF & RFPHY Test Specification
Core Version	5.3
Standard:	RFPHY.TS.p20
Test Spec Errata(s):	NA
PICS:	RFPHY.ICS.p8
TCRL version:	2023-1
Test procedure(s):	C-EMW-06 Bluetooth RF and Low Energy RFPHY Conducted Testing
Summary:	IN COMPLIANCE
Test Engineer:	Gavin Yang Gavin Yang
Approved by (name / position & signature):	Gavin Yang Gavin Yang Jimmy Chang Project Manager Jimmy Chang 2024-01-03
Report Revision:	01 V
Date of issue:	2024-01-03



FCC CERTIFICATE



TCB

GRANT OF EQUIPMENT AUTHORIZATION

Certification Issued Under the Authority of the Federal Communications Commission By:

Telefication B.V. Edisonstraat 12a Zevenaar, NL-6902 PK Netherlands

Mediawave Intelligent Communication LTD. 5F-1,NO81,Shuili Rd,East Dist

Attention: TIEN DER YEH, C.T.O

Hsinchu City, 300 Taiwan

Date of Grant: 10/30/2020

Application Dated: 10/29/2020

NOT TRANSFERABLE

EQUIPMENT AUTHORIZATION is hereby issued to the named GRANTEE, and is VALID ONLY for the equipment identified hereon for use under the Commission's Rules and Regulations listed below.

FCC IDENTIFIER:

2AXKL-MWBTRT6M
Mediawave Intelligent Communication LTD.
Digital Transmission System
Bluetooth module Name of Grantee:

Equipment Class: Notes: Modular Type: Limited Single Modular

Frequency Range (MHZ) **2402.0** - **2480.0** Output Frequency Emission **Grant Notes** FCC Rule Parts Watts Tolerance Designator

15C 0.0024

Modular Approval. Power output listed is conducted. This grant is valid only when the module is sold to OEM integrators and must be installed by the OEM or OEM integrators. The antennas used for this transmitter as shown in this filing must be installed to provide a separation distance of at least 20 cm from all persons and must not be co-located or operating in conjunction with any other antenna or transmitter. End-users may not be provided with the module installation instructions.OEM integrators and end-users must be provided with transmitter operating conditions for satisfying RF exposure compliance.

Certificate No.: 202180972/AA/00

Ramy Nabod Product Assessor



CE CERTIFICATE

Test Report Certification

Issued Date: Nov. 03, 2020

Report No. : 2090018R-E3032100003



Product Name : Bluetooth module

: Mediawave Intelligent Communication LTD. Applicant

: 5F-1,NO81,Shuili Rd,East Dist,Hsinchu City 300,Taiwan(R.O.C.) Address

Manufacturer : Liansong Metal Products Factory

Address : A Building, Mapu'ao Industrial Area, Sanlian Village, Fenggang

Town, Dongguan City, Guangdon Province, China.

MediaWave Trade Name Model No. : VT-RT6M **EUT Voltage** : DC 3.3V Testing Voltage : DC 3.3V

Applicable Standard : ETSI EN 300 328 V2.2.2 (2019-07)

Laboratory Name : Hsin Chu Laboratory

Address : No.372-2, Sec. 4, Zhongxing Rd., Zhudong Township, Hsinchu

County 310, Taiwan, R.O.C.

TEL: +886-3-582-8001 / FAX: +886-3-582-8958

Test Result : Complied

Documented By

(Carol Tsai / Senior Engineering Adm. Specialist)

Tested By

(Lion Wang / Engineer)

Approved By

(Louis Hsu / Deputy Manager)



MIC CERTIFICATE

telefication by The Netherlands Chamber of Commerce 51565536 www.telefication.com



Certificate

Radio Equipment in JAPAN

No: 201-200823 / 00

Telefication, operating as Conformity Assessment Body (CAB ID Number: 201) with respect to Japan, declares that the listed product complies with the Technical Regulations Conformity Certification of Specified Radio equipment (ordinance of MPT N° 37,1981)

Product description: Bluetooth module Trademark: MediaWave Type designation: VT-RT6M Hardware / Software version: V1 / V1

Manufacturer: Liansong Metal Products Factory

Address: A Building, Mapu'ao Industrial Area, Sanlian Village, Fenggang Town

City: Dongguan City, Guangdon

Country: China

This certificate is granted to:

Name: Mediawave Intelligent Communication LTD.

Address: 5F-1,NO81,Shuili Rd,East Dist

City: 300 Hsinchu Country: Taiwan

This certificate has THREE Annexes.

Zevenaar, 30 October 2020

CAB

David Chen David Chen

Product Assessor



NCC CERTIFICATE

德凱認證股份有限公司

電信管制射頻器材型式認證證明

證照字號:型式字第 AH 號

Product Certification

PC040

者: 名威智慧通訊有限公司

址: 新竹市東區千甲里水利路 81 號 5 樓 二、地

之一、之三

商: 東莞市聯崧電子科技有限公司 三、製

稱: Bluetooth module 四、器 名

牌: MediaWave 五、廠 六、型 號: VT-RT6M

七、發射功率(電場強度); 2402MHz~2480MHz; 3.78 dBm

八、エ 率:同上述第七點

九、審 期 ; 111年 10月 27日

十、審驗合格標籤式樣!

(((CCAH22Y20030T0



- 2. 請依主管機關或相關技術規範規定於指定位置標示正體中文警語
- 3. 電信管制射頻器材內建螢幕或須連接螢幕始能操作者,第一點標籤、 型號或正體中文警語標示得以螢幕顯示代之,並於包裝盒、使用手冊 或說明書載明操作方式。
- 4. 於網際網路販賣電信管制射頻器材者,應於該網際網路網頁標示其型 號及審驗合格標籤或符合性聲明標籤資訊。但最終產品得僅標示其型 號及其組裝之非隨插即用射頻模組(組件)之審驗合格標籤資訊。
- 5. 以取得審驗證明之完全射頻模組 (組件) 組裝成完全最終產品後,取 得該完全射頻模組(組件)之審驗證明者,應於該完全最終產品販賣 前,檢附標註完全最終產品廠牌、型號及外觀照片之電子檔案,向原 驗證機關 (構)登錄。
- 6. 審驗合格標籤及符合性聲明標籤屬取得審驗證明者所有。
- 7. 取得型式認證證明或符合性聲明證明者得授權他人於同廠牌同型號之 電信管制射頻器材或非隨插即用射頻模組(組件)使用審驗合格標籤

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